

TECHNICAL DATA DATA SHEET 4028, Rev. A

SILICON SCHOTTKY RECTIFIER DIE Ultra Low Reverse Leakage 200°C Operating Temperature

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging
- Out Performs 150 Volt Ultrafast Rectifiers

Maximum Ratings:

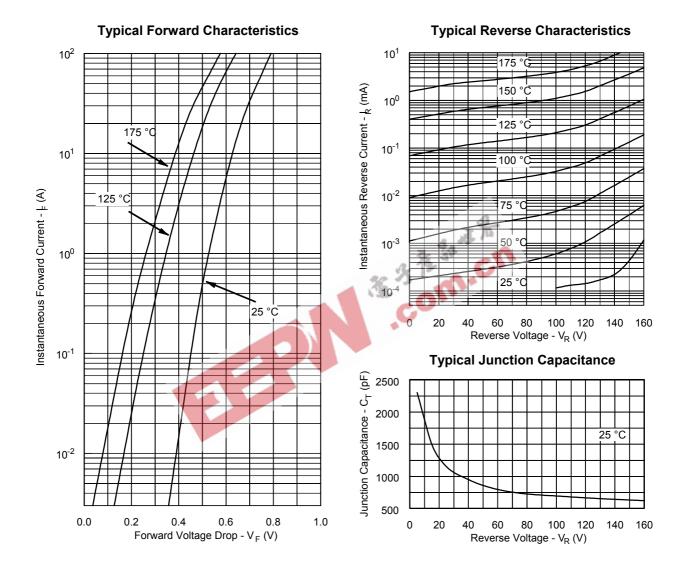
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	150	٧
Max. Average Forward	I _{F(AV)}	50% duty cycle, rectangular	120	Α
Current		wave form		
Max. Peak One Cycle Non-	I _{FSM}	8.3 ms, Sine pulse (1)	1650	Α
Repetitive Surge Current				
Max. Junction Temperature	T_J	-	-65 to +200	°C
Max. Storage Temperature	T _{stq}	-	-65 to +200	°C

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 120A, Pulse, T _J = 25 °C	0.87	V
	V_{F2}	@ 120A, Pulse, T _J = 125 °C	0.72	V
Max. Reverse Current	I _{R1}	@V _R = 150V, Pulse,	3.0	mA
		T _J = 25 °C		
	I _{R2}	@V _R = 150V, Pulse,	48	mA
		T _J = 125 °C		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	3000	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV (p-p)}$		

(1) in SHD package

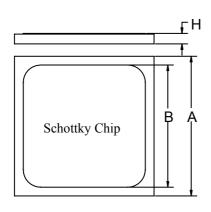
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SD275SC150A/B/C

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Mechanical Dimensions: In Inches / mm





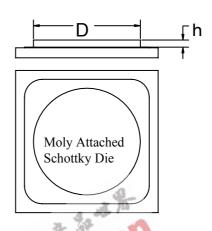


Figure 2

Top side(Anode) metallization:

A = A1 - 25 kÅ minimum, Figure 1

B = Ag - 30 kÅ minimum, Figure 1

C = Au - 12 kÅ min, Figure 2

Bottom side (Cathode) metallization: A, B, C = Ti/Ni/Ag - 30 kÅ minimum.

A	В	D	Н	h
0.275±0.003	0.267±0.003	0.220±0.005	0.0155±0.001	0.011±0.002

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